

# SANYO Semiconductors DATA SHEET

## RD2006FR—Diffused Junction Silicon Diode

### **Ultrahigh-Speed Switching Diode**

#### **Features**

- $V_F=1.75V \max (I_F=20A)$
- VRRM=600V
- $t_{rr}=21ns$  (typ.)
- · Halogen free compliance

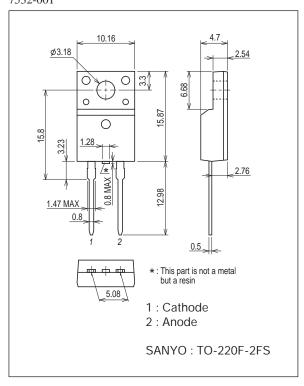
#### **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

| Parameter                       | Symbol           | Conditions                   | Ratings     | Unit |
|---------------------------------|------------------|------------------------------|-------------|------|
| Repetitive Peak Reverse Voltage | V <sub>RRM</sub> | DC bias                      | 600         | V    |
| Average Output Current          | I <sub>0</sub>   |                              | 20          | А    |
| Surge Forward Current           | I <sub>FSM</sub> | Sine wave, 10ms single pulse | 220         | Α    |
| Junction Temperature            | Tj               |                              | 150         | °C   |
| Storage Temperature             | Tstg             |                              | -55 to +150 | °C   |

#### **Package Dimensions**

unit : mm (typ) 7532-001



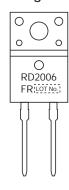
#### **Product & Package Information**

• Package : TO-220F-2FS

• JEITA, JEDEC : SC-67

• Minimum Packing Quantity : 50 pcs./magazine

#### Marking



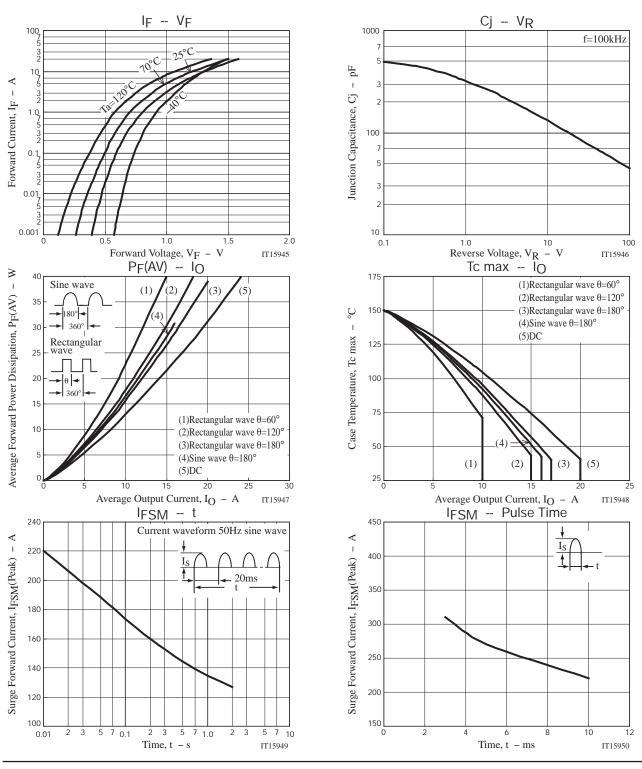
#### **Electrical Connection**

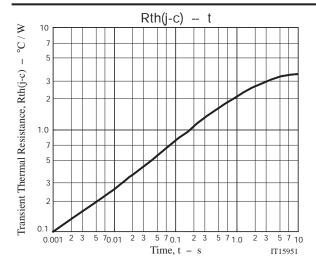


#### RD2006FR

#### Electrical Characteristics at Ta=25°C

| Parameter             | Symbol            | Conditions   | Ratings |     |      | Unit   |
|-----------------------|-------------------|--|---------|-----|------|--------|
|                       |                   |  | min     | typ | max  | OTHE   |
| Reverse Voltage       | VR                | I <sub>R</sub> =1mA                                      | 600     |     |      | V      |
| Forward Voltage       | VF                | IF=20A   |         | 1.6 | 1.75 | V      |
| Reverse Current       | IR                | V <sub>R</sub> =600V                                     |         |     | 100  | μΑ     |
| Reverse Recovery Time | t <sub>rr</sub> 1 | I <sub>F</sub> =10A, di / dt=100A/μs                     |         |     | 50   | ns     |
|                       | t <sub>rr</sub> 2 | IF=0.5A, IR=1A   |         | 21  |      | ns     |
| Thermal Resistance    | Rth(j-c)          | Between the junction part and the case smoothing current |         |     | 3.5  | °C / W |





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